Octal Buffers/Line Drivers With 3 State Outputs

HITACHI

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Description

The HD74BC240A provides high drivability and operation equal to or better than high speed bipolar standard logic IC by using Bi-CMOS process. The device features low power dissipation that is about 1/5 of high speed bipolar logic IC, when the frequency is 10 MHz. The device has eight inverter drivers with three state outputs in a 20 pin package. This device is a non inverting buffer and has two active low enables ($1\overline{G}$ and $2\overline{G}$). Each enable independently controls 4 buffers.

Features

- Input/Output are at high impedance state when power supply is off.
- Built in input pull up circuit can make input pins be open, when not used.
- TTL level input
- Wide operating temperature range $Ta = -40 \text{ to} + 85^{\circ}\text{C}$

Function Table

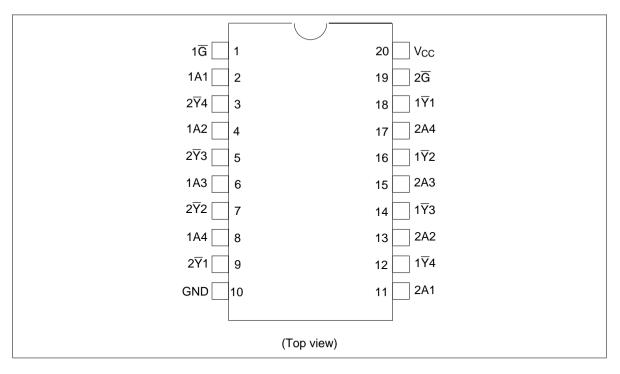
Inputs

G	A	Output \(\overline{Y} \)
Н	X	Z
L	Н	L
L	L	Н

H : High levelL : Low levelX : ImmaterialZ : High impedance



Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Rating	Unit	
Supply voltage	V _{cc}	-0.5 to +7.0	V	
Input diode current	I _{IK}	±30	mA	_
Input voltage	V _{IN}	-0.5 to +7.5	V	
Output voltage	V_{OUT}	-0.5 to +7.5	V	_
Off state output voltage	$V_{\text{OUT(off)}}$	-0.5 to +5.5	V	
Storage temperature	Tstg	-65 to +150	°C	

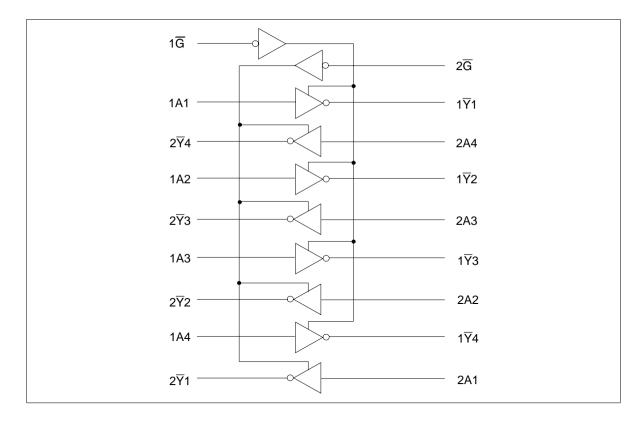
Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Min	Тур	Max	Unit
Supply voltage	V _{cc}	4.5	5.0	5.5	V
Input voltage	V _{IN}	0	_	V _{cc}	V
Output voltage	V_{OUT}	0	_	V _{cc}	V
Operating temperature	Topr	-40	_	85	°C
Input rise/fall time*1	t _r , t _f	0	_	8	ns/V

Note: 1. This item guarantees maximum limit when one input switches.
Waveform: Refer to test circuit of switching characteristics.

Logic Diagram



Electrical Characteristics (Ta = -40° C to $+85^{\circ}$ C)

Item	Symbol	$V_{cc}(V)$	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}		2.0	_	V	
	V _{IL}		_	0.8	V	
Output voltage	V _{OH}	4.5	2.4	_	V	$I_{OH} = -3 \text{ mA}$
		4.5	2.0	_	V	$I_{OH} = -15 \text{ mA}$
	V _{OL}	4.5	_	0.5	V	I _{OL} = 48 mA
		4.5	_	0.55	V	I _{OL} = 64 mA
Input diode voltage	V _{IK}	4.5	_	-1.2	V	$I_{IN} = -18 \text{ mA}$
Input current	I ₁	5.5	_	-250	μΑ	$V_{IN} = 0 V$
		5.5	_	1.0	μΑ	V _{IN} = 5.5 V
		5.5	_	100	μΑ	$V_{IN} = 7.0 \text{ V}$
Short circuit output current*1	Ios	5.5	-100	-225	mA	V _{IN} = 0 or 5.5 V
Off state output current	I _{OZH}	5.5	_	50	μΑ	V ₀ = 2.7 V
	I _{OZL}	5.5	_	-50	μΑ	$V_0 = 0.5 \ V$
Supply current	I _{CCL}	5.5	_	27.5	mA	$V_{IN} = 0$ or 5.5 V All outputs is "L"
	I _{CCH}	5.5	_	2.5	mA	$V_{IN} = 0$ or 5.5 V All outputs is "H"
	I _{CCZ}	5.5	_	2.5	mA	$V_{IN} = 0$ or 5.5 V All outputs is "Z"
	I _{CCT} *2	5.5	_	1.5	mA	$V_{IN} = 3.4 \text{ or } 0.5 \text{ V}$

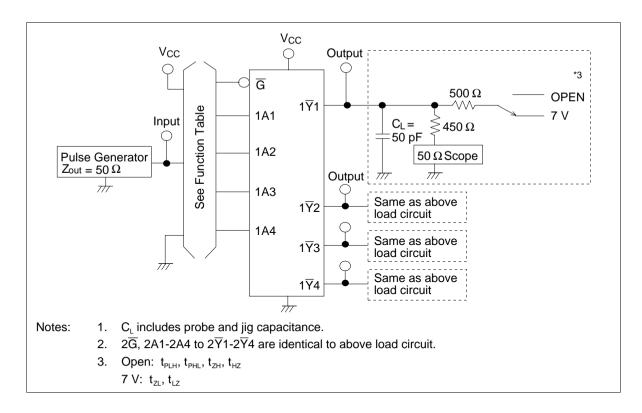
Notes: 1. Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

^{2.} When input by the TTL level, it shows I_{cc} increase at per one input pin.

Switching Test Method $(C_L = 50 \text{ pF})$

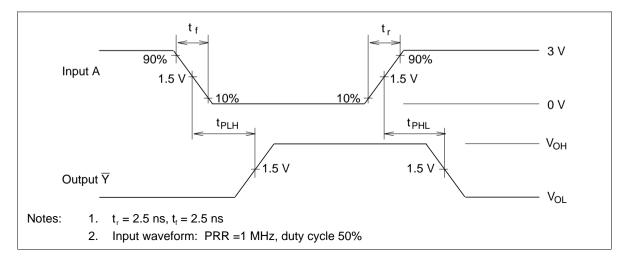
		Ta = 25°C V _{cc} = 5.0 V		Ta = -40 to 85° C V _{cc} = 5.0 V $\pm 10\%$			
Item	Symbol	Min	Max	Min	Max	Unit	Test Conditions
Propagation delay time	t _{PLH}	3.0	6.0	3.0	7.0	ns	See under figure
	t _{PHL}	3.0	6.0	3.0	7.0	_	
Output enable time	t_{ZH}	3.0	8.0	3.0	10.0	ns	_
	t_{zL}	3.0	8.0	3.0	10.0		
Output disable time	t_{HZ}	3.0	7.0	3.0	9.0	ns	
	t _{LZ}	3.0	7.0	3.0	9.0		
Input capacitanse	C_{IN}	3.0(Typ	p)	_		pF	$V_{IN} = V_{CC}$ or GND
Output capacitance	C _o	15.0(Ty	/p)	_		pF	$V_{o} = V_{cc}$ or GND

Test Circuit

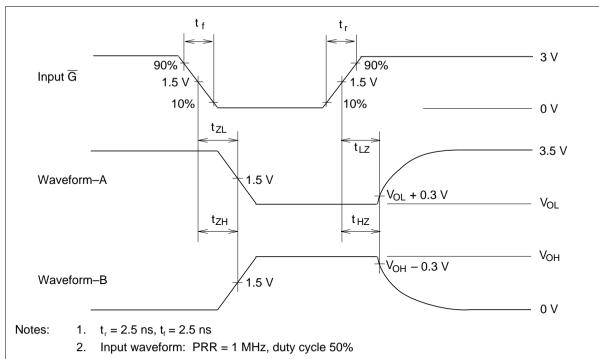


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Waveforms-1



Waveforms-2



- 3. Waveform-A shows input conditions such that the output is "L" level when enable by the output control.
- 4. Waveform-B shows input conditions such that the output is "H" level when enable by the output control.

	HD/4BC240A
Package Dimensions	
	Unit: mm

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